

View Online at <https://aerobasegroup.com/nsn/5961-01-064-6882>

Inclosure Material:

Ceramic

Overall Length:

0.300 inches

Overall Height:

0.085 inches

Overall Width:

0.280 inches

Component Name And Quantity:

4 transistor

Mounting Method:

Terminal

Semiconductor Material:

Silicon all transistor

Voltage Rating In Volts Per Characteristic:

-40.0 collector to base voltage, dc all transistor and -40.0 collector to emitter voltage/static/base open all transistor and -5.0 emitter to base voltage, dc all transistor

Current Rating Per Characteristic:

-1.50 amperes source cutoff current all transistor

Maximum Operating Temperature Per Measurement Point:

200.0 degrees celsius junction

Special Features:

All transistor junction pattern arrangement: pnp

Test Data Document:

88818-a532a068 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Terminal Type And Quantity:

14 printed circuit

Shelf Life:

N/a

Unit Of Measure:

--

Demilitarization:

No

Fig:

A110a0